# PE53111

**Document Category: Product Brief** 



Single Channel Switch LNA Module, 2.3 GHz - 2.7 GHz

### Features

- Wide frequency range with internal matching
- Integrates single-channel LNA with bypass and high power switch
- · Max RF input power
  - 5W Pavg for long term
  - 10W Pavg for short term
- 1.4 dB noise figure
- 30 dBm OIP3/ 34 dB gain at full gain mode
- +105 °C operating temperature
- Low power consumption: 90 mA per channel
- Compact package size of 32-lead 5x5 mm

## Applications

- 4G/4.5G TD-LTE macro/micro cell
- Pre-5G/5G massive MIMO systems
- Receiver protection system

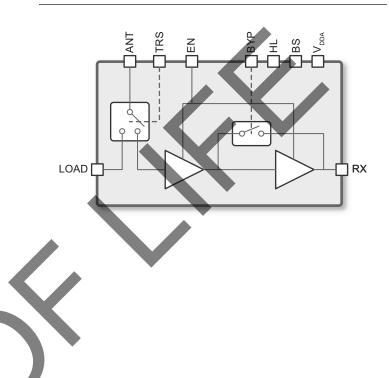


Figure 1 • PE53111 Functional Diagram

### **Product Description**

The PE53111 is a highly integrated front-end module targeted for wireless infrastructure applications such as TDD macro/micro base stations and MIMO application. It is designed for use at the front end of a receiver chain for TDD-based systems. The PE53111 is ideally suited for 4G or next-generation 5G solutions, or small cell applications.

The single-channel receiver integrates an LNA with bypass function and a high power switch. The PE53111 can be utilized across the 2.3 – 2.7 GHz frequency range with internal impedance matching networks.

This receiver utilizes pSemi's UltraCMOS SOI technology which supports input RF power signal up to 5W average power, assuming 8 dB PAR and very low noise figure, excellent linearity and very low power consumption.



### **Ordering Information**

Table 1 lists the available ordering codes for the PE53111 as well as available shipping methods.

#### Table 1 • Order Codes for PE53111

Order Codes	Description	Packaging	Shipping Method
PE53111A-Z	PE53111 Switch and LNA	32-lead 5x5 mm LGA	3000 units/T&R
EK53111-01	PE53111 Evaluation kit	Evaluation kit	1/Box

### **Document Categories**

#### Advance Information

The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

#### **Preliminary Specification**

The datasheet contains preliminary data. Additional data may be added at a later date. pSemi reserves the right to change specifications at any time without notice in order to supply the best possible product.

#### **Product Specification**

The datasheet contains final data. In the event pSemi decides to change the specifications, pSemi will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

#### **Product Brief**

The product brief contains summary product information.

#### Sales Contact

For additional information, contact Sales at sales@psemi.com.

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